







	<p>IPD60R750E6</p>
	<p>Hersteller-Teilenummer: IPD60R750E6</p> <p>Hersteller / Marke: International Rectifier (Infineon Technologies)</p> <p>Teil der Beschreibung: IPD60R750E6 Infineon Technologies</p> <p>Datenblätter:  IPD60R750E6.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 27219 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	IPD60R750E6
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	IPD60R750E6 Infineon Technologies
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	27219 pcs Stock
Serie	CoolMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	PG-TO252-3
Verlustleistung (max)	48W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	5.7A (Tc)
Rds On (Max) @ Id, Vgs	750 mOhm @ 2A, 10V
VGS (th) (Max) @ Id	3.5V @ 170µA
Gate Charge (Qg) (Max) @ Vgs	17.2nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	373pF @ 100V
Verpackung	Tape & Reel (TR)

IPD60R750E6 ist neu im Original, Suche IPD60R750E6 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPD60R750E6 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPD60R750E6: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IPD60R600P7ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 650V 6A TO252-3</p>	 <p>IPD60R650CEATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 600V TO-252-3</p>	 <p>IPD60R650CEBTMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 600V 7A TO252</p>	 <p>IPD60R750E6ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 600V 5.7A TO252</p>
 <p>IPD60R800CEATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 600V TO-252-3</p>	 <p>IPD60R800CEAUMA1 International Rectifier (Infineon Technologies) CONSUMER</p>	 <p>IPD60R800CE INF IPD60R800CE INF</p>	 <p>IPD60R750E6BTMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 600V 5.7A TO252-3</p>

heiße Teile

Mehr

⊗ IPD50R650CE	↔ IPD50R950CE	⇒ IPD530N15N3	D IPD530N15N3G	↔ IPD530N15NG
⊣ IPD60N25N3G	⊗ IPD60N10S4L-12	D IPD60R1K0CE	⇒ IPD60R1K4C6	↔ IPD60R1K5CE
⊗ IPD60R2K0C6	⊣ IPD60R360P	⊗ IPD60R380C6	↔ IPD60R380E6	↔ IPD60R380P6
D IPD60R385CP	⊗ IPD60R3K3C6	⊣ IPD60R400CE	⊗ IPD60R450E6	↔ IPD60R520C6
⇒ IPD60R520CP	↔ IPD60R600C6	⊗ IPD60R600CP	⊣ IPD60R600E6	↔ IPD60R600P6
↔ IPD60R800CE	⇒ IPD60R950C6	D IPD640N06LG	⊗ IPD64CN10NG	⊣ IPD65R1K4C6
⊗ IPD65R250C6	D IPD65R250E6	⇒ IPD65R380C6	↔ IPD65R380E6	↔ IPD65R420CFD
⊣ IPD65R420CFDA	⊗ IPD65R600C6	↔ IPD65R600E6	⇒ IPD65R660CFD	↔ IPD65R950C6
⊗ IPD65R950CFD	⊣ IPD70N03S4L-04	⊗ IPD70N03S4L04XT	D IPD70N04S3-07	↔ IPD70N10S3-12
↔ IPD70N10S3L-12	⊗ IPD70P04P4-09	⊣ IPD70P04P4L-08	⊗ IPD75N04S4-06	↔ IPD78CN10NG

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